NCE N-Channel Super Trench Power MOSFET

Description

The NCEP0160F uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

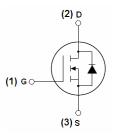
- V_{DS} =100V, I_D =60A $R_{DS(ON)}$ =9.2m Ω (typical) @ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

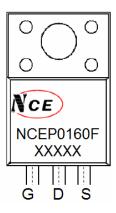
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220F top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP0160F	NCEP0160F	TO-220F	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	100	V	
Gate-Source Voltage	V _G S	±20	V	
Drain Current-Continuous	I _D	60	Α	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	42.4	Α	
Pulsed Drain Current	I _{DM}	240	Α	
Maximum Power Dissipation	P _D	40	W	
Derating factor		0.27	W/℃	
Single pulse avalanche energy (Note 5)	E _{AS}	290	mJ	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$	



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NCEP0160F

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	R _{eJC}	3.75	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit
		•			
BV _{DSS}	V _{GS} =0V I _D =250μA	100		-	V
I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	2	3	4	V
R _{DS(ON)}	V _{GS} =10V, I _D =30A	-	9.2	10.8	mΩ
g FS	V _{DS} =5V,I _D =30A	-	45	-	S
C _{lss}	\/ -50\/\/ -0\/	-	2500	-	PF
Coss	, ,	-	273	-	PF
C _{rss}	F=1.UIVIFIZ	-	27	-	PF
		•			
t _{d(on)}		-	13	-	nS
t _r	V_{DD} =50 V , I_D =30 A	-	8.5	-	nS
t _{d(off)}	V_{GS} =10 V , R_{G} =4.7 Ω	-	29	-	nS
t _f		-	4	-	nS
Qg	\/ _F0\/	-	37		nC
Q _{gs}		-	14		nC
Q_{gd}	V _{GS} -10V	-	8		nC
V_{SD}	V _{GS} =0V,I _S =60A	-		1.2	V
I _S		-	-	60	Α
t _{rr}	$T_{J} = 25^{\circ}C, I_{F} = I_{S}$	-	78		nS
Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	149		nC
	BV _{DSS} I _{DSS} I _{DSS} I _{DSS} I _{DSS} I _{DSS} I _{DSS} V _{GS(th)} R _{DS(ON)} g _{FS} C _{ISS} C _{OSS} C _{TSS} C _{TSS} T _d (on) t _r t _d (off) t _f Q _g Q _{gS} Q _{gd} V _{SD} I _S I _S t _{rr} I _S t _{rr} T _{rr}	BV _{DSS}	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	BV _{DSS} V _{GS} =0V I _D =250μA 100 I _{DSS} V _{DS} =100V,V _{GS} =0V - I _{GSS} V _{GS} =±20V,V _{DS} =0V - V _{GS} (th) V _{DS} =V _{GS} ,I _D =250μA 2 3 R _{DS} (ON) V _{GS} =10V, I _D =30A - 9.2 g _{FS} V _{DS} =5V,I _D =30A - 45 C _{ISS} V _{DS} =50V,V _{GS} =0V, F=1.0MHz - 273 C _{OSS} C _{TSS} - 2500 - 273 t _d (on) T _C - 273 - 273 t _{GSS} V _{DS} =50V,I _D =30A - 8.5 - 29 t _f - 4 - 29 - 37 Q _g V _{DS} =50V,I _D =30A, V _{GS} =10V - 14 - 8 V _{SD} V _{GS} =0V,I _S =60A - - - - 78 V _{SD} V _{GS} =0V,I _S =60A - - - - - - - - - - - -	BV _{DSS}

Notes:

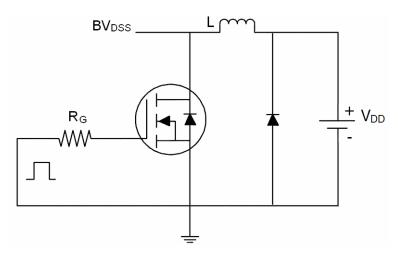
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω



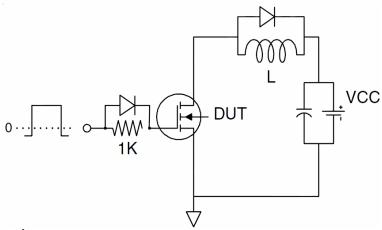
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Test Circuit

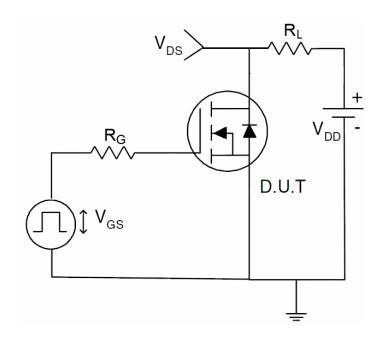
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics

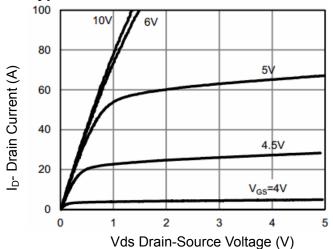


Figure 1 Output Characteristics

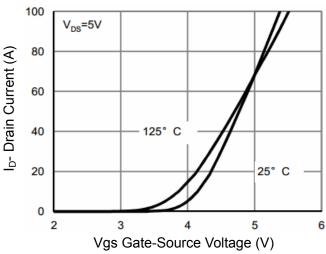


Figure 2 Transfer Characteristics

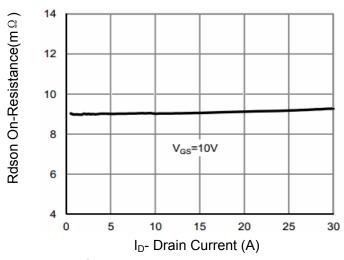


Figure 3 Rdson- Drain Current

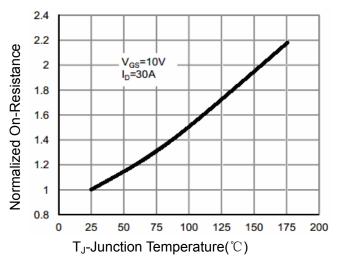


Figure 4 Rdson-JunctionTemperature

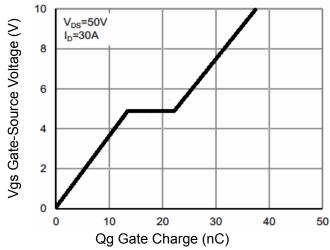


Figure 5 Gate Charge

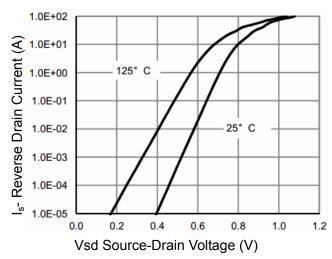


Figure 6 Source- Drain Diode Forward



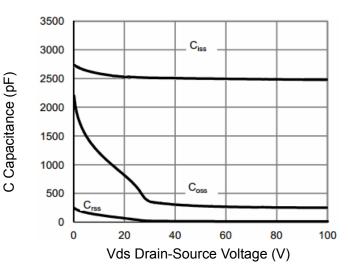


Figure 7 Capacitance vs Vds

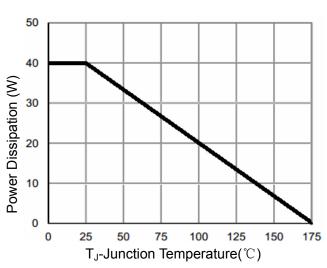


Figure 9 Power De-rating

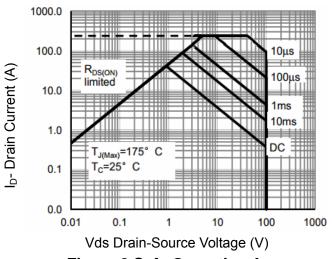


Figure 8 Safe Operation Area

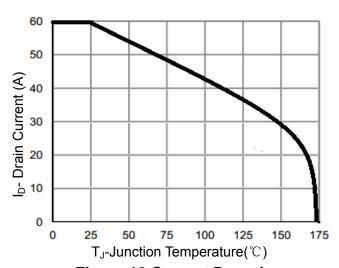


Figure 10 Current De-rating

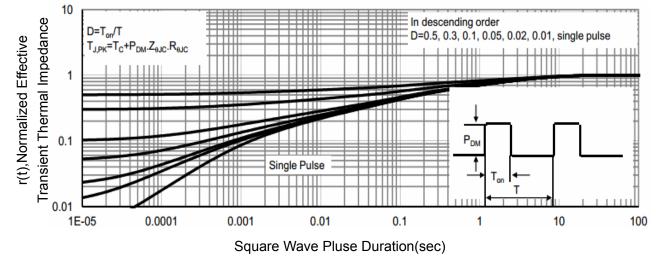
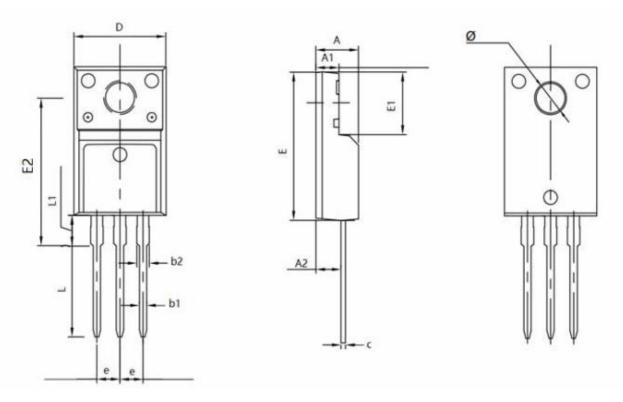


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220F Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	4.500	4.900	0.177	0.193	
A1	2.340	2.740	0.092	0.108	
A2	2.560	2.960	0.101	0.117	
b1	0.700	0.900	0.028	0.035	
b2	1.180	1.580	0.046	0.062	
С	0.400	0.600	0.016	0.024	
D	9.960	10.360	0.392	0.408	
E	15.670	15.970	0.617	0.629	
E1	6.500	6.900	0.256	0.272	
E2	15.500	16.100	0.610	0.634	
е	2.540 TYP		0.100 TYP		
Φ	3.080	3.280	0.121	0.129	
L	12.640	13.240	0.498	0.521	
L1	3.030	3.430	0.119	0.135	



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